

N-Channel 100 V (D-S) MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A) ^{a, e} Q _g (Ty				
100	0.223 at V _{GS} = 10 V	3	4.2 nC			
100	0.235 at V _{GS} = 4.5 V	2	4.2110			

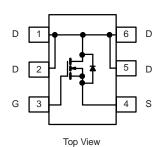
FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFET
- Low On-Resistance
- 100 % R_g Tested
- Compliant to RoHS Directive 2002/95/EC



FREE

SOT23-6



APPLICATIONS

• DC/DC Converters, High Speed Switching

Parameter		Symbol	Limit	Unit	
Drain-Source Voltage	V _{DS}	100	V		
Gate-Source Voltage		V _{GS}	± 20	V	
	T _C = 25 °C		3 ^e		
Continuous Proin Current (T. – 150 °C)	T _C = 70 °C		2 ^e		
Continuous Drain Current (T _J = 150 °C)	T _A = 25 °C	I _D	1.5 ^{b, c}		
	T _A = 70 °C		1.4 ^{b, c}	A	
Pulsed Drain Current (t = 100 µs)		I _{DM}	10		
Continuous Source-Drain Diode Current	T _C = 25 °C	I-	2.1		
Continuous Source-Diam Diode Current	T _A = 25 °C	I _S	1.1 ^{b, c}		
	T _C = 25 °C		1.5		
Maximum Power Dissipation	T _C = 70 °C	P _D	0.6	W	
Maximum Fower Dissipation	T _A = 25 °C	L L D	1.3 ^{b, c}		
	T _A = 70 °C		0.8 ^{b, c}		
Operating Junction and Storage Temperature	T _J , T _{stg}	- 55 to 150	°C		
Soldering Recommendations (Peak Tempera		230			

THERMAL RESISTANCE RATINGS								
Parameter	Symbol	Typical	Maximum	Unit				
Maximum Junction-to-Ambient ^{b, d}	t ≤ 5 s	R _{thJA}	75	100	°C/W			
Maximum Junction-to-Foot (Drain)	Steady State	R_{thJF}	40	50				

Notes

- a. Based on $T_C = 25$ °C.
- b. Surface mounted on 1" x 1" FR4 board.
- c t = 5 s
- d. Maximum under steady state conditions is 166 °C/W.
- e. Package limited.



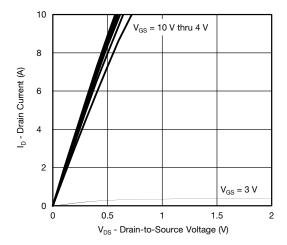
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static						•
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	100			V
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$	I _D = 250 μA		30		mV/°C
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	10 = 200 μΛ		- 4.8		
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_{D} = 250 \mu A$	2.0		4.0	V
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA
Zara Cata Valtana Duain Comment	I _{DSS}	V _{DS} = 100 V, V _{GS} = 0 V			1	μΑ
Zero Gate Voltage Drain Current		V _{DS} = 100 V, V _{GS} = 0 V, T _J = 70 °C			10	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \le 5 \text{ V}, V_{GS} = 10 \text{ V}$	10			Α
Dania Carana Ca Otata Daniata and	В	$V_{GS} = 10 \text{ V}, I_D = 1.5 \text{ A}$		0.223	0.246	Ω
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 1 \text{ A}$		0.235	0.259	
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 1.5 A		13		S
Dynamic ^b				"		·
Input Capacitance	C _{iss}			237		
Output Capacitance	C _{oss}	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		100		pF
Reverse Transfer Capacitance	C _{rss}			42		
Total Gate Charge	Qg	V _{DS} = 15 V, V _{GS} = 10 V, I _D = 1.5 A		8.2	13	nC
				4.2	7	
Gate-Source Charge	Q_{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 1.5 \text{ A}$		1.4		
Gate-Drain Charge	Q_{gd}			1.4		
Gate Resistance	R _g	f = 1 MHz	2.5	12.6	25.2	Ω
Turn-On Delay Time	t _{d(on)}			6	12	
Rise Time	t _r	V_{DD} = 15 V, R_L = 3.4 Ω		20	30	ns
Turn-Off Delay Time	t _{d(off)}	$I_D \cong 1.4 \text{ A}, V_{GEN} = 4.5 \text{ V}, R_g = 1 \Omega$		14	21	
Fall Time	t _f			10	20	
Turn-On Delay Time	t _{d(on)}			3	6	
Rise Time	t _r	V_{DD} = 15 V, R_L = 3.4 Ω		11	20	
Turn-Off Delay Time	t _{d(off)}	$I_D \cong 1.4 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 1 \Omega$		20	30	
Fall Time	t _f			7	14	
Drain-Source Body Diode Characteristic	cs			<u> </u>	l	ı
Continuous Source-Drain Diode Current	I _S	T _C = 25 °C			2.1	_
Pulse Diode Forward Current	I _{SM}				10	A
Body Diode Voltage	V _{SD}	$I_S = 1.4 \text{ A}, V_{GS} = 0 \text{ V}$		0.82	1.2	V
Body Diode Reverse Recovery Time	t _{rr}			13	20	ns
Body Diode Reverse Recovery Charge	Q _{rr}	1 4 4 A 41/44 40 A/v- T 05 20		6	12	nC
Reverse Recovery Fall Time	t _a	$I_F = 1.4 \text{ A}, \text{ dI/dt} = 10 \text{ A/}\mu\text{s}, T_J = 25 ^{\circ}\text{C}$		8		ns
Reverse Recovery Rise Time	t _b			5		

- a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %. b. Guaranteed by design, not subject to production testing.

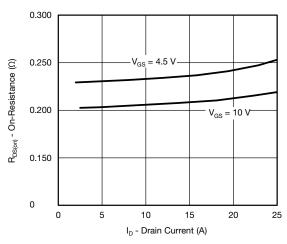
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



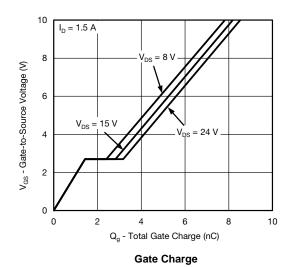
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

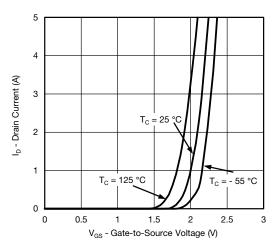


Output Characteristics

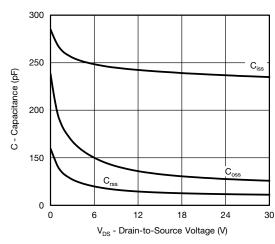


On-Resistance vs. Drain Current and Gate Voltage

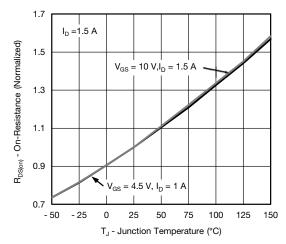




Transfer Characteristics



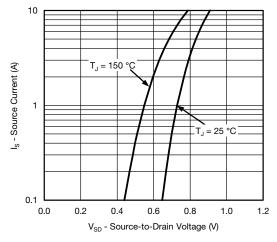
Capacitance



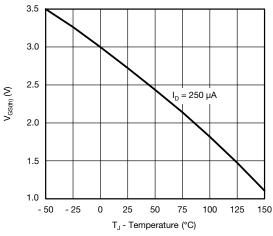
On-Resistance vs. Junction Temperature



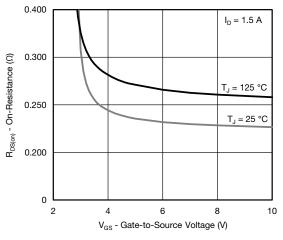
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



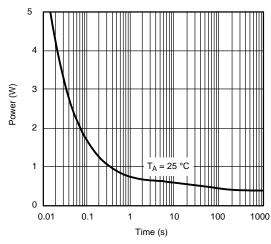
Source-Drain Diode Forward Voltage



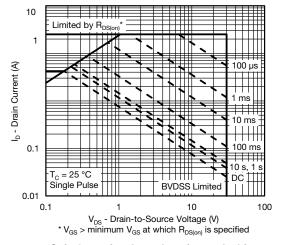
Threshold Voltage



On-Resistance vs. Gate-to-Source Voltage

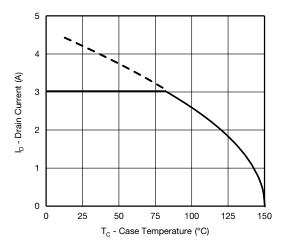


Single Pulse Power (Junction-to-Ambient)

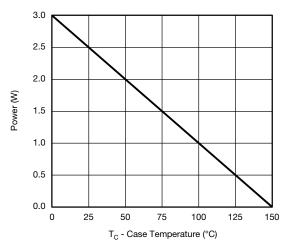


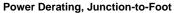
Safe Operating Area, Junction-to-Ambient

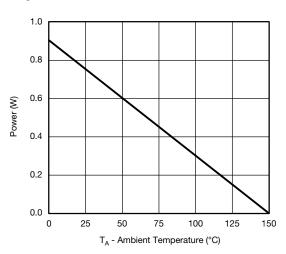
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Current Derating*





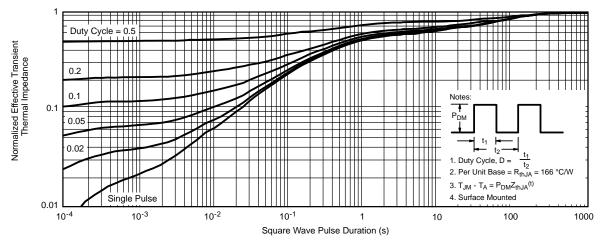


Power Derating, Junction-to-Ambient

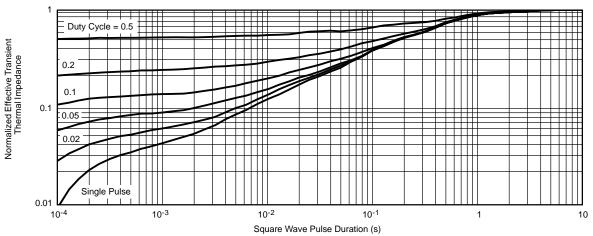
^{*} The power dissipation P_D is based on $T_{J(max.)}$ = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



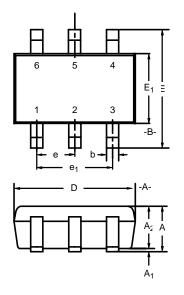
Normalized Thermal Transient Impedance, Junction-to-Ambient

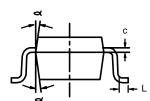


Normalized Thermal Transient Impedance, Junction-to-Foot



SOT23-6



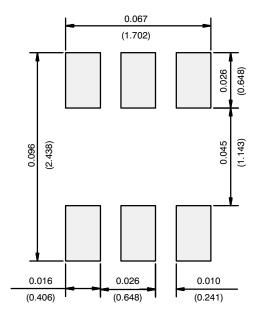


	MIL	LIMET	ERS	INCHES		
Dim	Min	Nom	Max	Min	Nom	Max
Α	0.90	_	1.10	0.035	_	0.043
A ₁	-	-	0.10	-	-	0.004
A ₂	0.80	_	1.00	0.031	_	0.039
b	0.15	_	0.30	0.006	_	0.012
С	0.10	_	0.25	0.004	_	0.010
D	1.80	2.00	2.20	0.071	0.079	0.087
Е	1.80	2.10	2.40	0.071	0.083	0.094
E ₁	1.15	1.25	1.35	0.045	0.049	0.053
е	0.65BSC			0.026BSC		
e ₁	1.20	1.30	1.40	0.047	0.051	0.055
L	0.10	0.20	0.30	0.004	0.008	0.012
8	7°Nom			7°Nom		

ECN: S-03946—Rev. B, 09-Jul-01 DWG: 5550



RECOMMENDED MINIMUM PADS FOR SOT23-6



Recommended Minimum Pads Dimensions in Inches/(mm)



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